

Silicon SP4T Surface Mount HMIC PIN Diode Switch **RoHS Compliant**

Rev. V5

Features

- Operates 50 MHz to 20 GHz
- Usable up to 26 GHz
- Low Insertion Loss
- High Isolation
- Low Parasitic Capacitance and Inductance
- **RoHS Compliant Surmount Package**
- Rugged, Fully Monolithic
- Glass Encapsulated Construction
- Up to +38 dBm C.W. Power Handling @ +25°C
- Silicon Nitride Passivation
- Polymer Scratch Protection
- Solderable

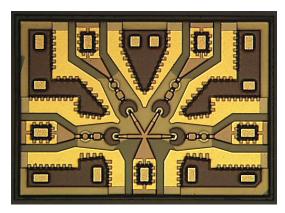
Description

The MASW-004103-1365 is a SP4T, surmount, broadband, monolithic switch using four sets of series and shunt connected PIN diodes. This device is designed for use in broadband, low to moderate signal, high performance, switch applications up to 20 GHz. It is a surface mountable switch configured for optimized performance and offers a distinct advantage over MMIC, beamlead and chip and wire hybrid designs. Because the PIN diodes of the MASW-004103-1365 are integrated into the chip and kept within close proximity, the parasitics typically associated with other designs that use individual components are kept to a minimum.

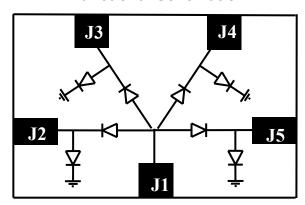
To minimize the parasitics and achieve high performance the MASW-004103-1365 is fabricated using M/A-COM Technology Solutions' patented HMIC™ (Heterolithic Microwave Integrated Circuit) process. This process allows the silicon pedestals, which form the series and shunt diodes or vias, to be imbeded in low loss, low dispersion glass. The combination of low loss glass and using tight spacing between elements results in an HMIC device with low loss and high isolation through low millimeter wave frequencies.

The topside is fully encapsulated with silicon nitride and also has an additional layer of polymer for scratch and impact protection. The protective coating guards against damage to the junction and the anode airbridges during handling and assembly.

On the backside of the chip gold metalized pads have been added to produce a solderable surmount device.



Functional Schematic



Pin Configuration

| Pin | Function | | | | |
|-----|----------|--|--|--|--|
| J1 | RFC | | | | |
| J2 | RF1 | | | | |
| J3 | RF2 | | | | |
| J4 | RF3 | | | | |
| J5 | RF4 | | | | |

Ordering Information

| Part Number | Package |
|--------------------|-------------------|
| MASW-004103-13650G | 50 piece gel pack |
| MASW-004103-13655P | 500 piece reel |
| MASW-004103-13650P | 3000 piece reel |
| MASW-004103-001SMB | Sample Test Board |

- North America Tel: 800.366.2266 Europe Tel: +353.21.244.6400
- India Tel: +91.80.43537383
- · China Tel: +86.21.2407.1588

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Electrical Specifications: $T_A = 25^{\circ}C$, $P_{IN} = 0$ dBm, $Z_0 = 50 \Omega$, 20 mA/-10 V

| Parameter | Conditions | Units | Min. | Тур. | Max. |
|-------------------------------|--|-------|----------------|----------------------|-------------------|
| Insertion Loss | 6 GHz 13 GHz 20 GHz | dB | _ _ _ | 0.5 0.8 1.2 | 0.6 1.0 1.5 |
| Isolation | 6 GHz 13 GHz 20 GHz | dB | 48 38 29 | 51 39 32 | |
| Input Return Loss | 6 GHz 13 GHz 20 GHz | dB | 17 13 12 | 21 17 16 | |
| Output to Output Isolation | 6 GHz 13 GHz 20 GHz | dB | _ _ _ | 53.5 41.5 31.5 | |
| Input 0.1dB Compression Point | 2 GHz | dB | _ | 36 | _ |
| IIP3 | 0.5 GHz, 5 MHz Spacing, +20dBm 1 GHz, 10 MHz Spacing, +20dBm 2 GHz, 10 MHz Spacing, +20dBm | dBm | _ _ _ | 60 63 64 | |
| Switching Speed ¹ | | ns | _ | 20 | _ |
| Voltage Rating ² | | V | _ | _ | 80 |

- 1. Typical Switching Speed measured from 10% to 90 % of detected RF signal driven by TTL compatible drivers.
- Maximum reverse leakage current in either the shunt or series PIN diodes shall be 0.5 μA maximum @ -80 volts.

Absolute Maximum Ratings 3,4

| Parameter | Absolute Maximum |
|-------------------------|---|
| Operating Temperature | -65 °C to +125 °C |
| Storage Temperature | -65 °C to +150 °C |
| Junction Temperature | +175 °C |
| Applied Reverse Voltage | -80 V |
| RF CW Incident Power | 38dBm CW @ 2GHz,+25°C 33dBm CW @ 20GHz,+25°C |
| Bias Current +25°C | ± 50 mA |

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM Tech does not recommend sustained operation at these survivability limits.

Combined maximum operating conditions for RF power, DC bias, & temperature: 33dBm CW, 20mA per Diode, +85°C

Static Sensitivity

These devices are rated at Class 1A Human Body Model. Proper ESD control techniques should be used when handling these devices.

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and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

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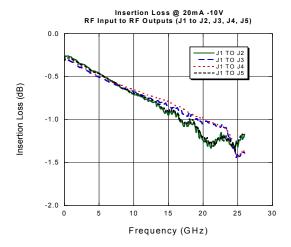
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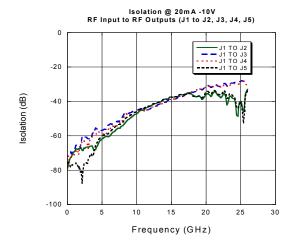


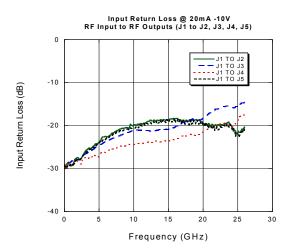
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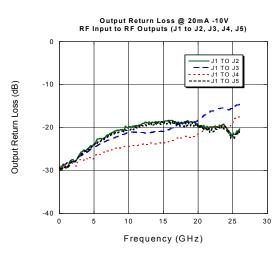
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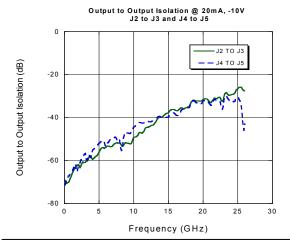
Typical Performance Curves



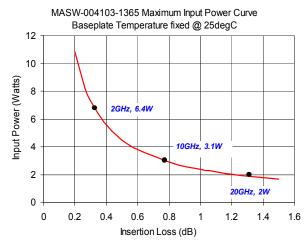








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Bias Control

Optimal operation of the MASW-004103-1365 is achieved by simultaneous application of negative DC voltage and current to the low loss switching arm and positive DC voltage and current to the remaining switching arms as shown in the applications circuit below. DC return is achieved via R2 on the RFC path. In the low loss state, the series diode must be forward biased with current and the shunt diode reverse biased with voltage. In the isolated arm, the shunt diode is forward biased with current and the series diode is reverse biased with voltage.

Driver Connections

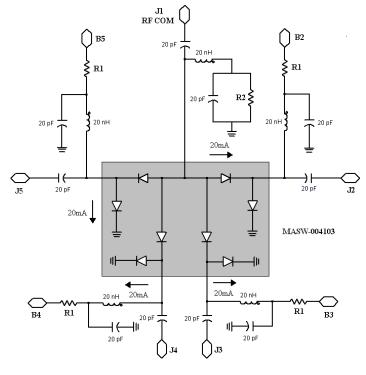
| Control Level (DC Currents and Voltages) | | | Condition of RF Output | | Condition of RF Output | Condition of RF Output | |
|---|----------------------------|----------------------------|----------------------------|-----------|------------------------|------------------------|-----------|
| B2 | В3 | B4 | B5 | J1-J2 | J1-J3 | J1-J4 | J1-J5 |
| -15V at -20mA ⁵ | 6V at +20mA | 6v at +20mA | 6V at +20mA | Low Loss | Isolation | Isolation | Isolation |
| 6V at +20mA | -15V at -20mA ⁵ | 6V at +20mA | 6V at +20mA | Isolation | Low Loss | Isolation | Isolation |
| 6V at +20mA | 6V at +20mA | -15V at -20mA ⁵ | 6V at +20mA | Isolation | Isolation | Low Loss | Isolation |
| 6V at +20mA | 6V at +20mA | 6V at +20mA | -15V at -20mA ⁵ | Isolation | Isolation | Isolation | Low Loss |

^{5.} The voltage applied to the off arm is allowed to vary provided a constant current is applied through the shunt diode on the off arm.

Application Circuit 6,7,8,9,10

Example:

J1 to J2 \rightarrow Low Loss R1 = 250 Ω R2 = 450 Ω B2 = -15V B3, B4, B5 = 6V



Notes:

- 6. Assume Vf ~ 1V at 20mA
- 7. R1 = $5V / 0.02A = 250\Omega$; R2 = $9V / 0.02A = 450\Omega$
- 8. $P_{R1} = 0.02A \times 0.02A \times 250 = 0.1 \text{ W}$
- 9. P_{R2} = 0.02A x 0.02A x 450 = 0.18 W
- 10. Inductors shown in the above schematic are RF bias chokes. The operating bandwidth of a broad-band PIN diode switch is often dependent on the bias components, particularly the RF bias chokes. It is suggested that the response at the frequencies of interest be measured with all the bias components in place prior to installing of MASW-004103-1365.

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Outline Drawing and Footprint (All dims. in µm)

Top View Side View **Bottom View** 125 2245 2142 200 ,200 ,200 J4 J3 290 200 1605 200 DC & RF GND 200 J5 J2 200 200 290 `29 Jl 238 200 200

- 1) Bottom view shows the back metal foot print and mounting pads.
- 2) All dimension are +/-0.5 µm.
- 3) Ground radius is 200 µm and centered on the I/O Pad.
- 4) The center pad shown on the chip bottom view must be connected to RF and DC ground

| MASW-004103-1365 | | | | | |
|------------------|---------|---------|-------|-------|--|
| DIM | Inc | hes | m | m | |
| | MIN MAX | | MIN | MAX | |
| Width | 0.06220 | 0.06417 | 1.580 | 1.630 | |
| Length | 0.08740 | 0.08937 | 2.220 | 2.270 | |
| Thickness | 0.00394 | 0.00591 | 0.100 | 0.150 | |

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Sample Board

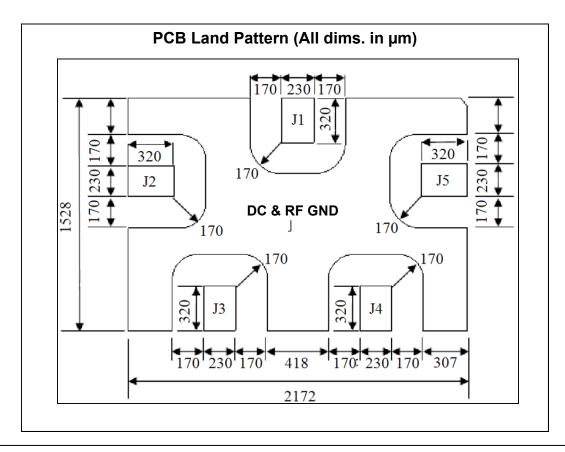
Samples test boards are available upon request

Handling Procedures

Attachment to a circuit board is made simple through the use of standard surface mount technology. Mounting pads are conveniently located on the bottom of the chip and are removed from the active junction locations making it well suited for solder attachment. Connections may be made onto hard or soft substrates via the use of 80Au/20Sn, or RoHS compliant solders. Typical re-flow profiles for provided in Application Note M538, "Surface Mounting Instructions" and can viewed in the Customer Support, Technical Resources section of the MA-COM Technology Solutions website at www.macomtech.com.

For applications where the average power is ≤ 1W, a thermally conductive silver epoxy may also be used. Cure per manufacturers recommended time and temperature. Typically 1 hour at 150°C.

When soldering these devices to a hard substrate, a solder re-flow method is preferred. A vacuum pick up tool with a soft tip is recommended while placing the chip. When soldering to soft substrates, such as Duroid, a soft solder is recommended at the circuit board to chip mounting pad interface to minimize stress due to any TCE mismatches that may exist. Position the die so that its mounting pads are aligned with the circuit board land pads. Solder reflow should not be performed by causing heat to flow through the top surface of the die to the back. Since the HMIC glass is transparent, the edges of the mounting pads can be visually inspected through the die after attachment is completed.



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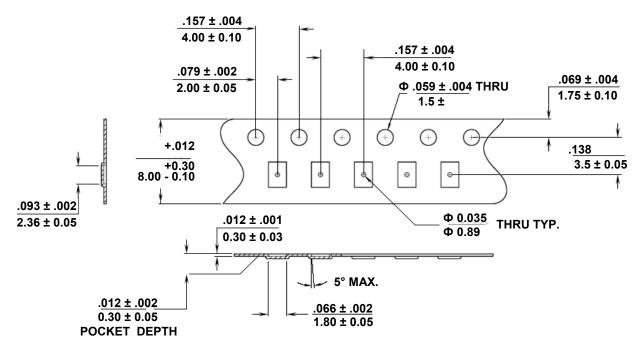


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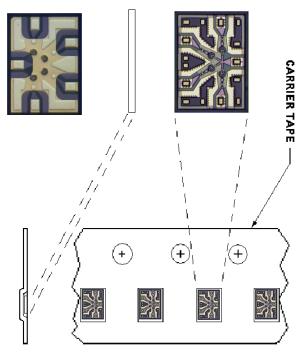
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Pocket Tape Information

Carrier Tape Dimensions



Chip Orientation in Tape



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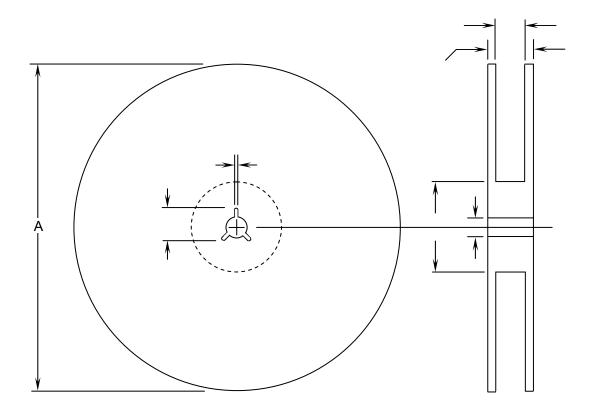
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Reel Information



| DIM | INCH | IES | MM | |
|-------|-------|-------|-------|-------|
| | MIN. | MAX. | MIN. | MAX. |
| Α | 6.980 | 7.019 | 177.3 | 178.3 |
| В | .059 | .098 | 1.5 | 2.5 |
| С | .504 | .520 | 12.8 | 13.2 |
| D | .795 | .815 | 20.2 | 20.7 |
| N | 2.146 | 2.185 | 54.5 | 55.5 |
| W_1 | .331 | .337 | 8.4 | 8.55 |
| W_2 | | .567 | | 14.4 |

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